NSN 5962-01-472-1949

Memory Microcircuit - Page 1 of 1



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| Operating Tempurature Range: |
|---|
| -55.0/+125.0 degrees celsius |
| Storage Tempurature Range: |
| -65.0/+150.0 degrees celsius |
| End Application: |
| F-15 |
| Features Provided: |
| Synchronous and 3-state output and low power and w/switch |
| Inclosure Material: |
| Ceramic |
| Inclosure Configuration: |
| Leadless flat pack |
| Output Logic Form: |
| Transistor-transistor logic |
| Product Name: |
| 8, 192-bit (1024x8 bipolar registered prom with programmable initialize input |
| Voltage Rating And Type Per Characteristic: |
| -0.5 volts power source and 7.0 volts power source |
| Memory Device Type: |
| Prom |
| Special Features: |
| 40 ns setup time/25 ns clock-to-output |
| Test Data Document: |
| 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). |
| Terminal Type And Quantity: |
| 32 leadless |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| Yes - demil/mli |
| Fiig: |
| A458a0 |
| |